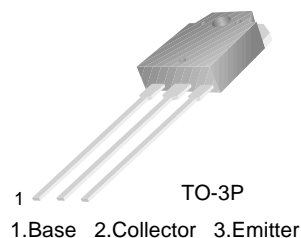


KSC4468

KSC4468

Audio Power Amplifier

- High Current Capability : $I_C=8A$
- High Power Dissipation
- Wide S.O.A
- Complement to KSA1695



NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings $T_C=25^\circ C$ unless otherwise noted

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	160	V
V_{CEO}	Collector-Emitter Voltage	140	V
V_{EBO}	Emitter-Base Voltage	6	V
I_C	Collector Current (DC)	8	A
I_{CP}	Collector Current (Pulse)	16	A
P_C	Collector Dissipation ($T_C=25^\circ C$)	80	W
T_J	Junction Temperature	150	$^\circ C$
T_{STG}	Storage Temperature	- 55 ~ 150	$^\circ C$

Electrical Characteristics $T_C=25^\circ C$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
BV_{CBO}	Collector-Base Breakdown Voltage	$I_C=5mA, I_E=0$	160			V
BV_{CEO}	Collector-Emitter Breakdown Voltage	$I_C=10mA, R_{BE}=\infty$	140			V
BV_{EBO}	Emitter-Base Breakdown Voltage	$I_E=5mA, I_C=0$	6			V
I_{CBO}	Collector Cut-off Current	$V_{CB}=80V, I_E=0$			0.1	mA
I_{EBO}	Emitter Cut-off Current	$V_{EB}=4V, I_C=0$			0.1	mA
h_{FE1} h_{FE2}	* DC Current Gain	$V_{CE}=5V, I_C=1A$ $V_{CE}=5V, I_C=6A$	60 20		200	
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C=5A, I_B=0.5A$			2.5	V
$V_{BE(on)}$	Base-Emitter ON Voltage	$V_{CE}=5V, I_C=1A$			1.5	V
f_T	Current Gain Bandwidth Product	$V_{CE}=5V, I_C=1A$		30		MHz
C_{ob}	Output Capacitance	$V_{CB}=10V, f=1MHz$		210		pF
t_{ON}	Turn ON Time	$V_{CC}=20V,$ $I_C=1A=10I_{B1}=-10I_{B2}$ $R_L=20\Omega$		0.26		μs
t_F	Fall Time			0.68		μs
t_{STG}	Storage Time			6.68		μs

* Pulse Test : $PW=20\mu s$

h_{FE} Classification

Classification	O	Y
h_{FE1}	60 ~ 120	100 ~ 200

Typical Characteristics

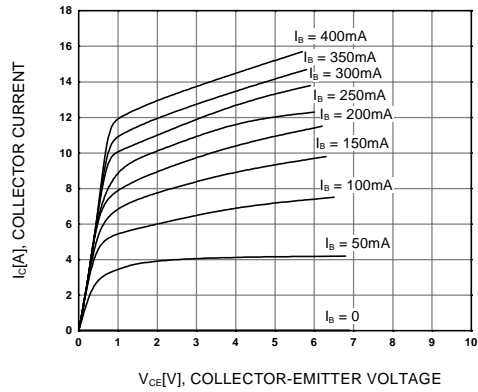


Figure 1. Static Characteristic

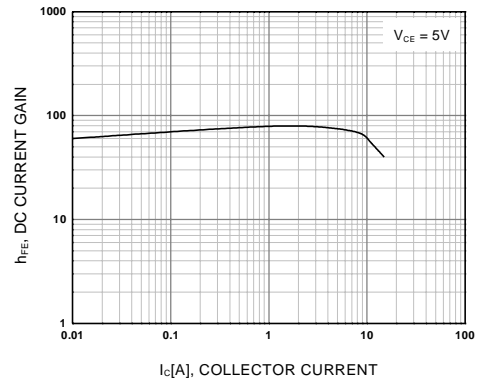


Figure 2. DC current Gain

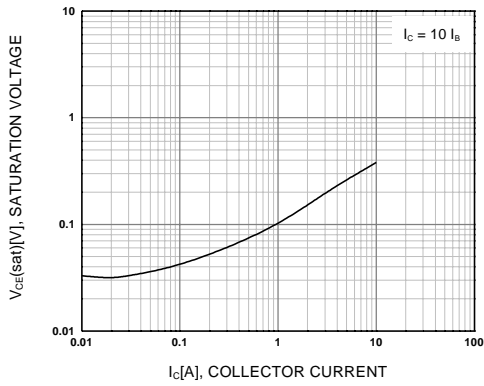


Figure 3. Collector-Emitter Saturation Voltage

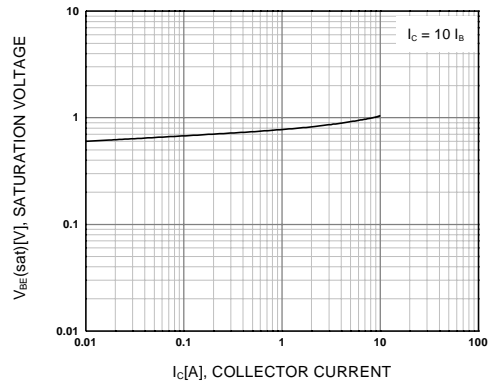


Figure 4. Base-Emitter Saturation Voltage

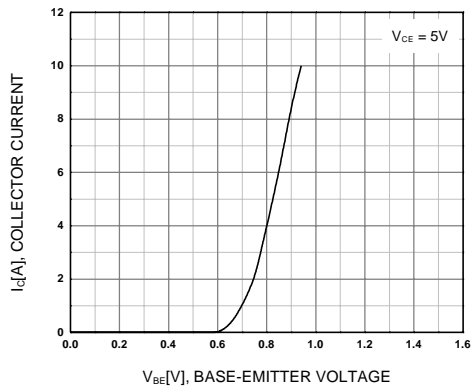


Figure 5. Base-Emitter On Voltage

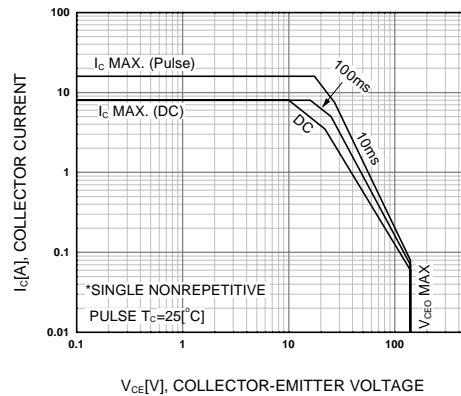
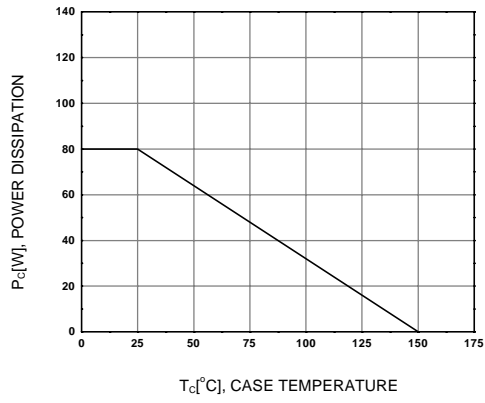
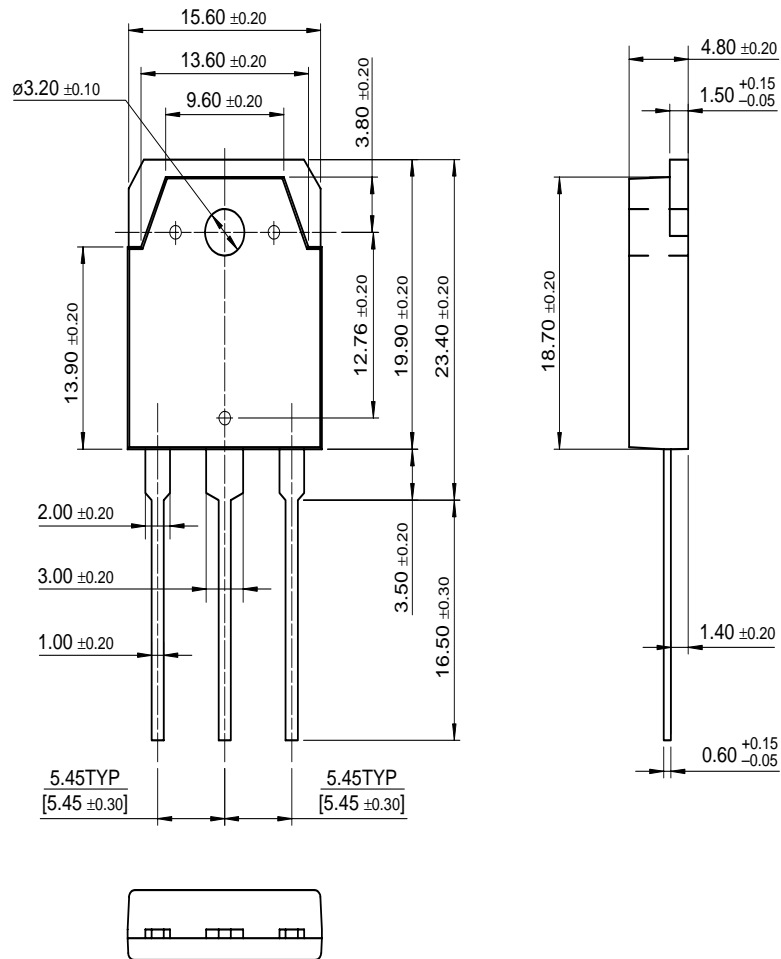


Figure 6. Safe Operating Area

Typical Characteristics (Continued)**Figure 7. Power Derating**

Package Dimensions

TO-3P



Dimensions in Millimeters

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